



# Precision Clock Synthesizer for Mobile PCs

#### **Features**

- Two copies of CPU clock with  $V_{DD}$  of  $2.5V \pm 5\%$
- 100 MHz or 66.6 MHz operation
- Six copies of PCI clock, (synchronous with CPU clock) 3.3V
- One copy of Ref. Clock @ 14.31818 MHz (3.3V<sub>TTL</sub>)
- Low cost 14.31818 MHz crystal oscillator input
- · Power management control
- Isolated core V<sub>DD</sub>, V<sub>SS</sub> pins for noise reduction
- 28-pin SSOP package (H)

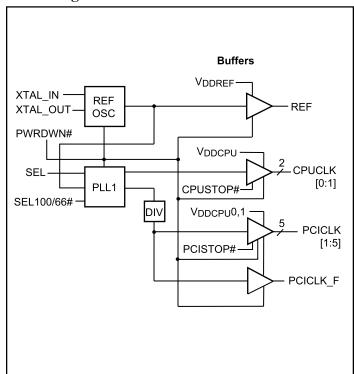
#### **Description**

The PI6C102 is a high-speed low-noise clock generator designed to work with the Pericom's PI6C18x clock buffer to meet all clock needs for Mobile Intel Architecture platforms. CPU and chipset clock frequencies of 66.6 MHz and 100 MHz are supported.

Split supplies of 3.3V and 2.5V are used. The 3.3V power supply powers a portion of the I/O and the core. The 2.5V is used to power the remaining outputs. 2.5V signaling follows JEDEC standard 8-X. Power sequencing of the 3.3V and 2.5V supplies is not required.

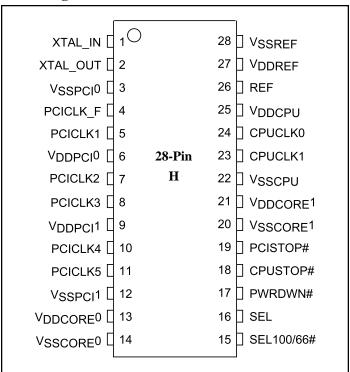
An asynchronous PWRDWN# signal may be used to orderly power down (or up) the system.

#### **Block Diagram**



#### **Pin Configuration**

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## **Pin Description**

Pin	Signal Name	Type	Qty.	Description
1	XTAL_IN	I	1	14.318 MHz crystal input
2	XTAL_OUT	О	1	14.318 MHz crystal output
3,12	V <sub>SSPCI</sub> [0:1]	ground	2	Ground for PCI clock outputs
4	PCICLK_F	О	1	Free running PCI clock output
5,7,8,10,11	PCICLK[1:5]	О	5	PCI clock outputs, TTL comatible 3.3V
6,9	V <sub>DDPCI</sub> [0:1]	power	2	Power for PCI clock outputs
21	V <sub>DDCORE 1</sub>	power	1	Isolated power for core
20	V <sub>SSCORE 1</sub>	ground	1	Isolated ground for core
15	SEL100/66#	I	1	Select pin for enabling 100 MHz or 66 MHz H = 100 MHz L = 66 MHz
16	SEL	I	1	Test or Active Mode Select
17	PWRDWN#	I	1	Powers down device when held LOW
18	CPUSTOP#	I	1	Stops CPU clocks LOW if held LOW
19	PCISTOP#	I	1	Stops PCI clocks LOW if held LOW
22	V <sub>SSCPU</sub>	ground	1	Ground for CPU outputs
23,24	CPUCLK[0:1]	О	2	CPU and Host clock outputs 2.5V
25	V <sub>DDCPU</sub>	power	1	Power for CPU outputs
26	REF	О	1	14.318 MHz clock output
27	V <sub>DDREF</sub>	power	1	Power for REF outputs
28	V <sub>SSREF</sub>	ground	1	Ground for REF outputs

## **Select Functions**

SEL100/66#	SEL	Function
0	0	Hi-Z
0	1	66 MHz active
1	0	Test Mode
1	1	100 MHz active

Function	Outputs					
Description	CPU [0:1]	PCI[0:5], PCIF	REF			
Hi-Z	Hi-Z	Hi-Z	Hi-Z			
Test Mode	TCLK/2	TCLK/6	TCLK			

# ${\bf Clock\,Enable\,Configuration}$

TCLK is a test clock over driven on he XTAL\_IN inpu during test mode.

CPU_STOP#	PCI_STOP#	PWR_DWN#	CPUCLK [0:1]	PCICLK[1:5]	PCICLK_F	Other Clocks	Crystal	VCO's
X	X	0	low	low	low	stopped	off	off
0	0	1	low	low	33 MHz	running	running	running
0	1	1	low	33 MHz	33 MHz	running	running	running
1	0	1	100/66 MHz	low	33 MHz	running	running	running
1	1	1	100/66 MHz	33 MHz	33 MHz	running	running	running

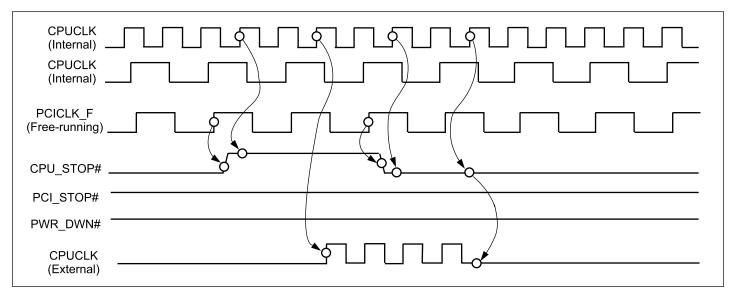


#### **Power Management Timing**

Signal	Signal State	Latency
Signal	Signal State	No. of rising edges of free running PCICLK
CPU_STOP#	0 (disabled)	1
	1 (enabled)	1
PCI_STOP#	0 (disabled)	1
	1 (enabled)	1
PWR_DWN#	1 (normal operation)	3ms
	0 (power down)	2 max.

#### **Notes:**

- Clock on/off latency is defined as the number of rising edges of free running PCICLKs between when the clock disable goes low/high to when the first valid clock comes out of the device.
- 2. Power-up latency is from when PWR\_DWN# goes inactive (HIGH) to when the first valid clocks are driven from the device.



**CPU STOP# Timing Diagram** 

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#### **Notes:**

- 1. All timing is referenced to the CPUCLK.
- 2. The Internal label means inside the chip and is a reference only.
- 3 CPU STOP# is an input signal that must be made synchronous to the free running PCI F.
- 4. ON/OFF latency shown in the diagram is 2 CPU clocks.
- 5. All other clocks continue to run undisturbed.
- 6. PWR\_DWN# and PCI\_STOP# are shown in a HIGH state.
- 7. Diagrams shown with respect to 66 MHz. Similar operation as CPU = 100 MHz.

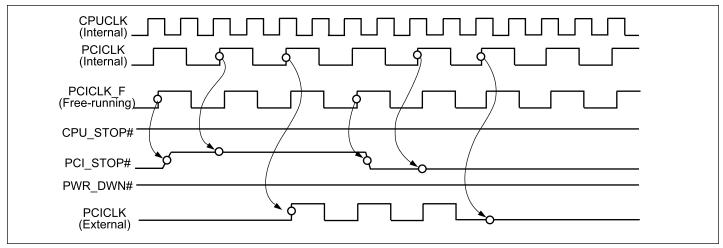
CPU\_STOP# is an input signal used to turn off the CPU clocks for low power operation. CPU\_STOP# is asserted asynchronously by the external clock control logic with the rising edge of free running PCI clock and is internally synchronized to the external PCICLK\_F output. All other clocks continue to run while the CPU clocks are

disabled. The CPU clocks are always stopped in a LOW state and started guaranteeing that the high pulse width is a full pulse. CPU clock on latency is 2 or 3 CPU clocks and CPU clock off latency is 2 or 3 CPU clocks.

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PCI STOP# is an input signal used to turn off PCI clocks for low power operation. PCI clocks are stopped in the LOW state and started with a guaranteed full high pulse width. There is ONLY one rising edge of external PCICLK after the clock control logic.



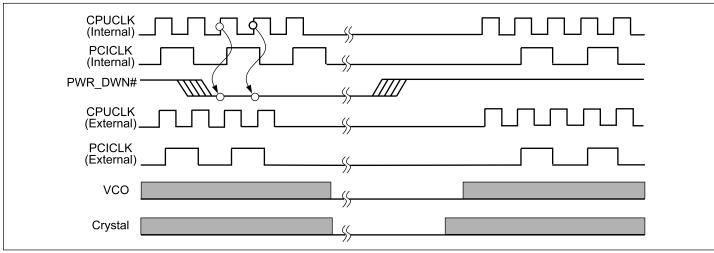
**PCI STOP# Timing Diagram** 

#### **Notes:**

- 1. All timing is referenced to the CPUCLK.
- PCI STOP# signal is an input signal which must be made synchronous to PCI F output.
- Internal means inside the chip.
- All other clocks continue to run undisturbed.
- PWR DWN# and CPU STOP# are shown in a high state.
- 6. Diagrams shown with respect to 66 MHz. Similar operation as CPU = 100 MHz.

The PWR DWN# is used to place the device in a very low power state. PWR DWN# is an asynchronous active low input. Internal clocks are stopped after the device is put in power-down mode.

The power-on latency is less than 3ms. PCI STOP# and CPU STOP# are "don't cares" during the power-down operations. The REF clock is stopped in the LOW state as soon as possible.



#### PWR\_DWN# Timing Diagram

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#### **Notes:**

- All timing is referenced to the CPUCLK.
- The Internal label means inside the chip and is a reference only.
- PWR DWN# is an asynchronous input and metastable conditions could exist. The signal is synchronized inside the part.
- The shaded sections on the VCO and the Crystal signals indicate an active clock.
- Diagrams shown wth respect to 66 MHz. Similar operation as CPU = 100 MHz.

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#### **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied0°C to +70°C
3.3V Supply Voltage to Ground Potential0.5V to +4.6V
2.5V Supply Voltage to Ground Potential0.5V to +3.6V
DC Input Voltage0.5V to +4.6V

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# DC Electrical Characteristics (V<sub>DDO3</sub>=+3.3V±5%, V<sub>DDO2</sub>=+2.5V±5%, T<sub>A</sub>=0°C to +70°C)

PI6C102 Condition	$\begin{aligned} \text{Max. 2.5V Supply Consumption} \\ \text{Max. discrete cap loads,} \\ \text{V}_{DDQ2} &= 2.625 \text{V} \\ \text{All static inputs} &= \text{V}_{DDQ3} \text{ or V}_{SS} \end{aligned}$	$\begin{aligned} \text{Max. 3.3V Supply Consumption} \\ \text{Max. discrete cap loads,} \\ \text{V}_{DDQ3} = 3.465\text{V} \\ \text{All static inputs} = \text{V}_{DDQ3} \text{ or V}_{SS} \end{aligned}$
Powerdown Mode (PWRDWN# =0)	100μΑ	500μΑ
Active 66 MHz SEL 100/66# = 0	72mA	170mA
Active 100 MHz SEL 100/66# = 1	100mA	170mA



# **DC Operating Specifications**

Symbol	Parameters	Conditions	Min.	Max.	Units
$V_{DD} = 3.3V \pm$	: 5%				
V <sub>IH3</sub>	Input high voltage	$V_{ m DD}$	2.0	V <sub>DD</sub> +0.3	17
V <sub>IL3</sub>	Input low voltage		V <sub>SS</sub> -0.3	0.8	V
$I_{\mathrm{IL}}$	Input leakage current	$0 < V_{IN} < V_{DD}$	-5	+5	μΑ
$V_{DD} = 2.5V \pm$	5%				
V <sub>OH2</sub>	Output high voltage	$I_{OH} = -1 \text{mA}$	2.0		17
V <sub>OL2</sub>	Output low voltage	$I_{OL} = 1 \text{mA}$		0.4	V
$V_{DD} = 3.3V =$	± 5%				
V <sub>OH3</sub>	Output high voltage	$I_{OH} = -1 \text{mA}$	2.4		<b>3</b> 7
V <sub>OL3</sub>	Output low voltage	$I_{OL} = 1 \text{mA}$		0.4	V
$V_{DD} = 3.3V \pm$	5%				
V <sub>POH</sub>	PCI Bus output high voltage	$I_{OH} = -1 \text{mA}$	2.4		17
V <sub>POL</sub>	PCI Bus output low voltage	$I_{OL} = 1 \text{mA}$		0.55	V
C <sub>IN</sub>	Input pin capacitance			5	
C <sub>XTAL</sub>	Xtal pins capacitance	13.5	18.0	22.5	pF
C <sub>OUT</sub>	Output pin capacitance			6	
L <sub>PIN</sub>	Pin Inductance			7	nН
TA	Ambient Temperature	No airflow	0	70	°C



# **Buffer Specifications**

Buffer Name	V <sub>DD</sub> Range(V)	Impedance (Ω)	Buffer Type
CPU	2.375 -2.625	13.5 - 45	Type 1
REF	3.135 - 3.465	20 - 60	Type 3
PCI	3.135 - 3.465	12 - 55	Type 5

# Type 1: CPU Clock Buffers (2.5V)

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
I <sub>OHMIN</sub>	Pull-up current	$V_{OUT} = 1.0V$	-27			
I <sub>OHMAX</sub>	Pull-up current	$V_{OUT} = 2.375V$			-27	
I <sub>OLMIN</sub>	Pull-down current	$V_{OUT} = 1.2V$	27			mA
I <sub>OLMAX</sub>	Pull-down current	$V_{OUT} = 0.3V$			30	
t <sub>RH</sub>	2.5V Type 1 output rise edge rate	2.5V ± 5% @ 0.4V-2.0V	1		4	V/ma
t <sub>FH</sub>	2.5V Type 1 output fall edge rate	2.5V ± 5% @ 2.0V-0.4V	1		4	V/ns

# **Type 3: REF (3.3V)**

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
I <sub>OHMIN</sub>	Pull-up current	$V_{OUT} = 1.0V$	-29			
I <sub>OHMAX</sub>	Pull-up current	$V_{OUT} = 2.375V$			-23	m A
I <sub>OLMIN</sub>	Pull-down current	$V_{OUT} = 1.2V$	29			mA
I <sub>OLMAX</sub>	Pull-down current	$V_{OUT} = 0.3V$			27	
t <sub>RH</sub>	3.3V Type 3 output rise edge rate	$3.3V \pm 5\%$ @ 0.4V-2.4V	0.5		2	V/ns
t <sub>FH</sub>	3.3V Type 3 output fall edge rate	3.3V ± 5% @ 2.4V-0.4V	0.5		2	V/IIS

# Type 5: PCI Clock Buffers (3.3V)

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units
I <sub>OHMIN</sub>	Pull-up current	$V_{OUT} = 1.0V$	-33			
I <sub>OHMAX</sub>	Pull-up current	$V_{OUT} = 3.135V$			-33	A
I <sub>OLMIN</sub>	Pull-down current	$V_{OUT} = 1.95V$	30			mA
IOLMAX	Pull-down current	$V_{OUT} = 0.4V$			38	
t <sub>RH</sub>	3.3V Type 5 output rise edge rate	3.3V ± 5% @ 0.4V-2.4V	1		4	V//ma
t <sub>FH</sub>	3.3V Type 5 output fall edge rate	3.3V ± 5% @ 2.4V-0.4V	1		4	V/ns



# **AC Timing**

Figure 1. Host Clock	D	66 MHz		100 MHz		TI	
to PCI CLK Offset	Parameters	Min.	Max.	Min.	Max.	Units	
t <sub>HKP</sub> (2.5V)	Host CLK period	15.0	15.5	10.0	10.5		
t <sub>HKH</sub> (2.5V)	Host CLK high time	5.2		3.0			
t <sub>HKL</sub> (2.5V)	Host CLK low time	5.0		2.8		ns	
thrise (2.5V)	Host CLK rise time	0.4	1.6	0.4	1.6		
t <sub>HFALL</sub> (2.5V)	Host CLK fall time	0.4	1.6	0.4	1.6		
tJITTER (2.5V)	Host CLK Jitter		250		250	ps	
Duty Cycle (2.5V)	Measured at 1.25V	45	55	45	55	%	
thskw (2.5V)	Host Bus CLK Skew		175		175	ps	
t <sub>PZL</sub> , t <sub>PZH</sub>	Output enable delay	1.0	8.0	1.0	8.0	ns	
tPLZ, tPHZ	Output disable delay	1.0	8.0	1.0	8.0		
thstb	Host CLK Stabilization from power-up		3		3	ms	
t <sub>PKP</sub>	PCI CLK period	30.0	∞	30.0	∞	ns	
t <sub>PKPS</sub>	PCI CLK period stability		500		500	ps	
tPKH	PCI CLK high time	12.0		12.0			
t <sub>PKL</sub>	PCI CLK low time	12.0		12.0		ns	
tpskw	PCI Bus CLK Skew		500		500	ps	
thpoffset	Host to PCI Clock Offset	1.5	4.0	1.5	4.0	ns	
t <sub>PSTB</sub>	PCI CLK Stabilization from power-up		3		3	ms	



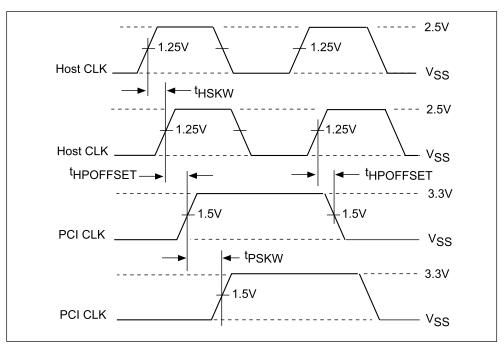


Figure 1. Host Clock and PCI CLK Timing

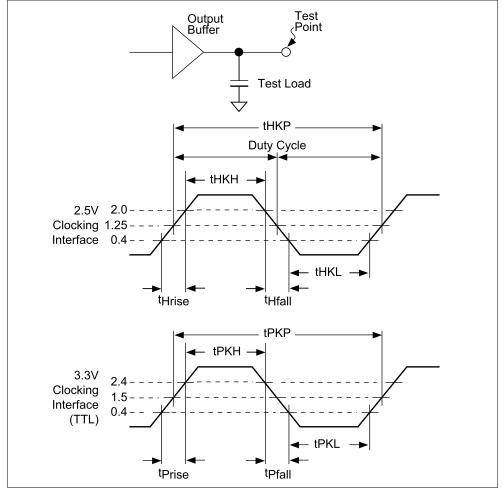
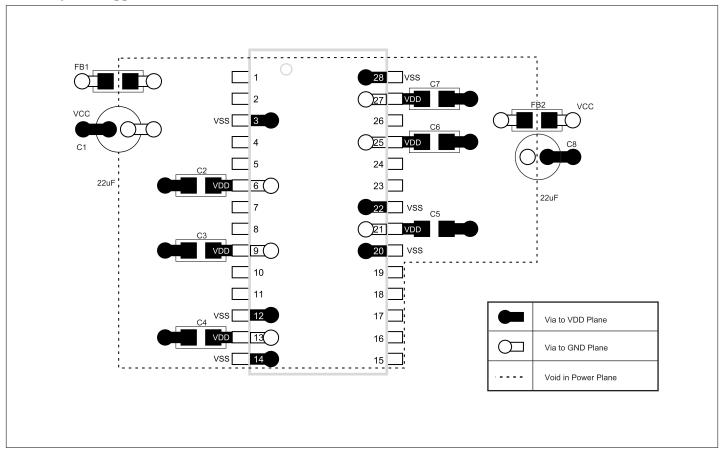


Figure 2. Clock Output Waveforms



# **PCB Layout Suggestion**



#### Note:

This is only a suggested layout. There may be alternate solutions depending on actual PCB design and layout.

As a general rule, C2-C7 should be placed as close as possible to their respective V<sub>DD</sub>.

Recommended capacitor values:

C2-C7 ..... 0.1µF, ceramic

C1, C8 ..... 22µF

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# Minimum and Maximum Expected Capacitive Loads

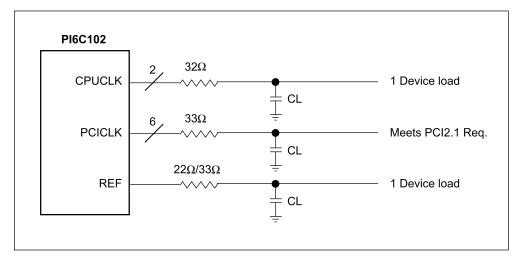
Clock	Min. Load	Max. Load	Units	Notes
CPU Clocks (HCLK)	10	20		1 device load, possible 2 loads
PCI Clocks (PCLK)	30	30	pF	Meets PCI 2.1 requirements
REF	10	20		1 device load

#### **Notes:**

- Maximum rise/fall times are guaranteed at maximum specified load for each type of output buffer.
- Minimum rise/fall times are guaranteed at minimum specified load for each type of output buffer.
- 3. Rise/fall times are specified with pure capacitive load as shown. Testing is done with an additional  $500\Omega$  resistor in parallel.

#### Design Guidelines to Reduce EMI

- 1. Place series resistors and CI capacitors as close as possible to the respective clock pins. Typical value for CI is 10pF. Series resistor value can be increased to reduce EMI provided that the rise and fall time are still within the specified values.
- 2. Minimize the number of "vias" of the clock traces.
- 3. Route clock traces over a continuous ground plane or over a continuous power plane. Avoid routing clock traces from plane to plane (refer to rule #2).
- 4. Position clock signals away from signals that go to any cables or any external connectors.



#### **Ordering Information**

P/N	Description		
PI6C102H	28-pin SSOP Package		

#### **Pericom Semiconductor Corporation**

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